	Application No.	Applicant(s)
Notice of Allowability	10/629,777	YOSHIKAWA, MASAHIRO
	Examiner M. 7/	Art Unit
	Tod T. Van Roy	2828
The MAILING DATE of this communication appears on the cover sheet with the correspondence address All claims being allowable, PROSECUTION ON THE MERITS IS (OR REMAINS) CLOSED in this application. If not included herewith (or previously mailed), a Notice of Allowance (PTOL-85) or other appropriate communication will be mailed in due course. THIS NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIGHTS. This application is subject to withdrawal from issue at the initiative of the Office or upon petition by the applicant. See 37 CFR 1.313 and MPEP 1308.		
1. This communication is responsive to <u>an RCE filed 05/12/2006</u> .		
2. ☑ The allowed claim(s) is/are <u>19,21 and 23-26</u> .		
3. Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).		
a) 🛮 All b) 🗌 Some* c) 🔲 None of the:		
1. 🛛 Certified copies of the priority documents have been received.		
2. Certified copies of the priority documents have been received in Application No :		
3. Copies of the certified copies of the priority documents have been received in this national stage application from the		
International Bureau (PCT Rule 17.2(a)).		
* Certified copies not received:		
Applicant has THREE MONTHS FROM THE "MAILING DATE" of this communication to file a reply complying with the requirements noted below. Failure to timely comply will result in ABANDONMENT of this application.  THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.		
4. A SUBSTITUTE OATH OR DECLARATION must be submitted. Note the attached EXAMINER'S AMENDMENT or NOTICE OF INFORMAL PATENT APPLICATION (PTO-152) which gives reason(s) why the oath or declaration is deficient.		
5. CORRECTED DRAWINGS ( as "replacement sheets") must be submitted.		
(a) ☐ including changes required by the Notice of Draftsperson's Patent Drawing Review ( PTO-948) attached		
1)  hereto or 2)  to Paper No./Mail Date		
(b) ☐ including changes required by the attached Examiner's Amendment / Comment or in the Office action of Paper No./Mail Date		
Identifying indicia such as the application number (see 37 CFR 1.84(c)) should be written on the drawings in the front (not the back) of each sheet. Replacement sheet(s) should be labeled as such in the header according to 37 CFR 1.121(d).		
<ol> <li>DEPOSIT OF and/or INFORMATION about the deposit of BIOLOGICAL MATERIAL must be submitted. Note the attached Examiner's comment regarding REQUIREMENT FOR THE DEPOSIT OF BIOLOGICAL MATERIAL.</li> </ol>		
•		
Attachment(s)	5. Thicking of Informal F	Optom Application (DTO 152)
1. Notice of References Cited (PTO-892)	<u> </u>	Patent Application (PTO-152)
2. Notice of Draftperson's Patent Drawing Review (PTO-948)	6. ☐ Interview Summary Paper No./Mail Da	te
<ol> <li>Information Disclosure Statements (PTO-1449 or PTO/SB/0 Paper No./Mail Date</li> </ol>	08), 7. ☐ Examiner's Amendi	ment/Comment
4. Examiner's Comment Regarding Requirement for Deposit of Biological Material	8. X Examiner's Statement	ent of Reasons for Allowance
- -	9.	

Art Unit: 2828

## **DETAILED ACTION**

## Response to Amendment

The examiner acknowledges the amending of claims 19, 21, and 24, as well as the cancellation of claim 22.

## Allowable Subject Matter

Claims 19, 21, and 23-26 are allowed.

The following is an examiner's statement of reasons for allowance:

Claim 19 is believed to be allowable as a vertical emitting laser including a current confining layer, protective film covering distinct components, and a compound semiconductor layer having a surface roughness of 5nm or less, after having an electrode formed thereupon, was not found to be taught in the prior art, nor an obvious combination of the prior art. Prior art such as Otoma (JP2002-009393) was found to teach a similar device type, while Saito (US 5945690) was found to teach compound semiconductors layers with surface roughness under 5nm. Otoma does not speak at all towards degrees of surface roughness, while Saito failed to teach the surface roughness values to be maintained after the electrode formation was complete. Namely the compound semiconductor layer with surface roughness of 5nm or less after having an electrode formed upon it is believed to be a unique feature to this device type.

Claims 21 and 23-26 are allowable as they depend from allowable claim 19.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably Art Unit: 2828

accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

## Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Tod T. Van Roy whose telephone number is (571)272-8447. The examiner can normally be reached on M-F.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Minsun Harvey can be reached on (571)272-1835. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

**TVR** 

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